

S16C70CE Thru S16C100CE

Schottky Barrier Power Rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

- * Low Forward Voltage.
- * Low Switching noise.
- * High Current Capacity

MAXIMUM RATINGS

- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- * Low Power Loss & High efficiency.
- * 150 Operating Junction Temperature
- * Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used Carries Underwriters Laboratory

Characteristic	Symbol	S16C				11
		70CE	80CE	90CE	100CE	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	70	80	90	100	V
RMS Reverse Voltage	V _{R(RMS)}	49	56	63	70	V
Average Rectifier Forward Current Total Device (Rated V _R),T _C =100	I _{F(AV)}	8.0 16			A	
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	16			A	
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I _{FSM}	150			A	
Operating and Storage Junction Temperature Range	T _J , T _{STG}	-65 to +150				

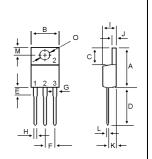
ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	S16C				Unit
		70CE	80CE	90CE	100CE	Unit
Maximum Instantaneous Forward Voltage ($I_F = 8 \text{ Amp } T_C = 25$) ($I_F = 8 \text{ Amp } T_C = 125$)	V _F	-	75 68	-	80 73	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25$) (Rated DC Voltage, $T_C = 125$)	I _R	0.: 20				mA

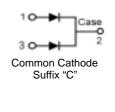


16 AMPERES 70-100 VOLTS





DIM	MILLIMETERS		
	MIN	MAX	
Α	14.68	15.32	
В	9.78	10.42	
С	5.02	6.52	
D	13.06	14.62	
Е	3.57	4.07	
F	2.42	2.66	
G	1.12	1.36	
Н	0.72	0.96	
I	4.22	4.98	
J	1.14	1.38	
К	2.20	2.98	
L	0.33	0.55	
Μ	2.48	2.98	
0	3.70	3.90	



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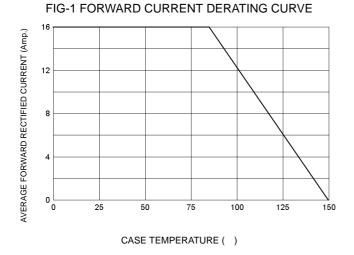
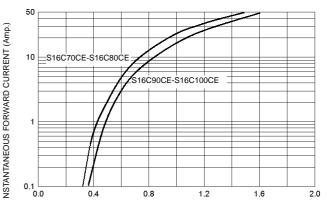
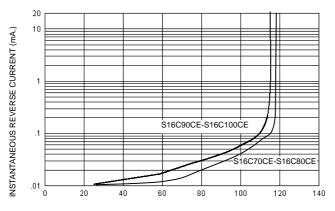


FIG-2 TYPICAL FORWARD CHARACTERISITICS



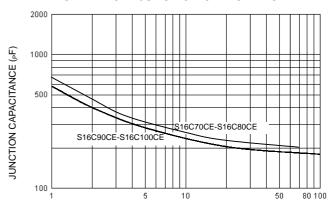
FORWARD VOLTAGE (Volts)

FIG-3 TYPICAL REVERSE CHARACTERISTICS

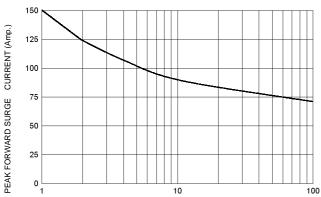


PERCENT OF RATED REVERSE VOLTAGE (%)

FIG-4 TYPICAL JUNCTION CAPACITANCE



REVERSE VOLTAGE (Volts)



NUMBER OF CYCLES AT 60 Hz

FIG-5 PEAK FORWARD SURGE CURRENT



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